NSN 5962-01-276-4796

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-276-4796 **Body Length:** Between 0.342 inches and 0.358 inches **Body Width:** Between 0.342 inches and 0.358 inches **Body Height:** Between 0.064 inches and 0.080 inches **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius **Storage Tempurature Range:**

-65.0/+150.0 degrees celsius

Features Provided:

High speed and high performance

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

8 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Pal

Terminal Type And Quantity:

20 leadless

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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